

SN74HCS594 8-Bit Shift Register With Schmitt-Trigger Inputs and Output Registers

1 Features

- Wide operating voltage range: 2 V to 6 V
- Schmitt-trigger inputs allow for slow or noisy input signals
- Low power consumption
 - Typical I_{CC} of 100 nA
 - Typical input leakage current of ±100 nA
- ±7.8-mA output drive at 6 V
- Extended ambient temperature range: –40°C to +125°C, T_A

2 Applications

- Output expansion
- LED matrix control
- 7-segment display control
- 8-bit data storage

3 Description

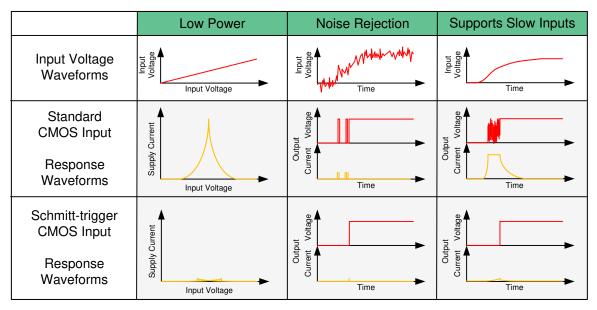
The SN74HCS594 device contains an 8-bit, serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. All inputs include Schmitt triggers, eliminating any erroneous data outputs due to slowedged or noisy input signals. The storage register has parallel outputs. Separate clocks and direct overriding clear (SRCLR, RCLR) inputs are provided for both the shift and storage register. A serial output ($Q_{H'}$) is provided for cascading.

Both the shift register (SRCLK) and storage register (RCLK) clocks are positive edge triggered. If both clocks are connected together, the shift register is one count pulse ahead of the storage register.

Device Information

Device information								
PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)						
SN74HCS594PW	TSSOP (16)	5.00 mm × 4.40 mm						
SN74HCS594D	SOIC (16)	9.90 mm × 3.90 mm						
SN74HCS594BQB	WQFN (16)	3.60 mm x 2.60 mm						
SN74HCS594DYY	SOT-23-THN (16)	4.20 mm x 2.00 mm						

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Benefits of Schmitt-trigger inputs



Table of Contents

1 Features	1
2 Applications	
3 Description	1
4 Revision History	
5 Pin Configuration and Functions	3
6 Specifications	
6.1 Absolute Maximum Ratings	
6.2 ESD Ratings	
6.3 Recommended Operating Conditions	
6.4 Thermal Information	4
6.5 Electrical Characteristics	5
6.6 Timing Characteristics	5
6.7 Switching Characteristics	
6.8 Operating Characteristics	
6.9 Typical Characteristics	8
7 Parameter Measurement Information	
8 Detailed Description	10
8.1 Overview	
8.2 Functional Block Diagram	
5	

8.3 Feature Description	10
8.4 Device Functional Modes	
9 Application and Implementation	13
9.1 Application Information	
9.2 Typical Application	14
10 Power Supply Recommendations	17
11 Layout	17
11.1 Layout Guidelines	
11.2 Layout Example	
12 Device and Documentation Support	18
12.1 Documentation Support	18
12.2 Receiving Notification of Documentation Upda	tes18
12.3 Support Resources	
12.4 Trademarks	
12.5 Electrostatic Discharge Caution	18
12.6 Glossary	
13 Mechanical, Packaging, and Orderable	
Information	

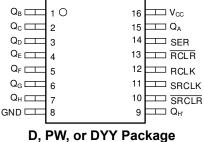
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

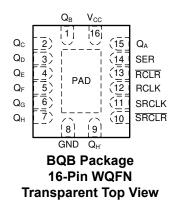
C	hanges from Revision * (October 2020) to Revision A (May 2021)	Page
•	Added DYY Package to Device Information Table	1
•	Added DYY Package pinout diagram and information to Pin Configuration and Functions	3
•	Added DYY and BQB Package to Thermal Information table	4



5 Pin Configuration and Functions



16-Pin SOIC, TSSOP, or SOT-23 Top View



Pin Functions

PIN		ТҮРЕ	DESCRIPTION			
NAME	NO.		DESCRIPTION			
Q _B	1	Output	Q _B output			
Q _C	2	Output	Q _C output			
Q _D	3	Output	Q _D output			
Q _E	4	Output	Q _E output			
Q _F	5	Output	Q _F output			
Q _G	6	Output	Q _G output			
Q _H	7	Output	Q _H output			
GND	8	_	Ground			
Q _{H'}	9	Output	Serial output, can be used for cascading			
SRCLR	10	Input	Shift register clear, active low			
SRCLK	11	Input	Shift register clock, rising edge triggered			
RCLK	12	Input	Output register clock, rising edge triggered			
RCLR	13	Input	Storage register clear, active low			
SER	14	Input	Serial input			
Q _A	15	Output	Q _A output			
V _{CC}	16	_	Positive supply			
Therma	al Pad ⁽¹⁾	_	The thermal pad can be connect to GND or left floating. Do not connect to any other signal or supply.			

1. BQB package only.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{cc}	Supply voltage		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V		±20	mA
I _{OK}	Output clamp current ⁽²⁾	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V		±20	mA
I _O	Continuous output current	$V_{O} = 0$ to V_{CC}		±35	mA
	Continuous current through V_{CC} or GN	D		±70	mA
TJ	Junction temperature ⁽³⁾			150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) Guaranteed by design.

6.2 ESD Ratings

			VALUE	UNIT
	Human-body model (HBM), per ANSI/ESDA/ JEDEC JS-001 ⁽¹⁾	±4000	V	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	2	5	6	V
VI	Input voltage	0		V _{CC}	V
Vo	Output voltage	0		V _{CC}	V
T _A	Ambient temperature	-40		125	°C

6.4 Thermal Information

		SN74HCS594					
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	D (SOIC)	BQB (WQFN)	DYY (SOT)	UNIT	
		16 PINS	16 PINS	16 PINS	16 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	141.2	122.2	108.4	186.2	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	78.8	80.9	77.3	109.1	°C/W	
$R_{\theta J B}$	Junction-to-board thermal resistance	85.8	80.6	74.4	111.0	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	27.7	40.4	12.6	18.0	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	85.5	80.3	74.5	110.9	°C/W	



		SN74HCS594				
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	D (SOIC)	BQB (WQFN)	DYY (SOT)	UNIT
		16 PINS	16 PINS	16 PINS	16 PINS	
R _{θJC(bot}	Junction-to-case (bottom) thermal resistance	N/A	N/A	54.3	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted).

	PARAMETER	TEST CC	NDITIONS	V _{cc}	MIN	ТҮР	MAX	UNIT
				2 V	0.7		1.5	
V _{T+}	Positive switching threshold			4.5 V	1.7		3.15	V
				6 V	2.1		4.2	
				2 V	0.3		1.0	
V _{T-} Negative switching threshold			4.5 V	0.9		2.2	V	
				6 V	1.2		3.0	
				2 V	0.2		1.0	
ΔV _T	Hysteresis (V _{T+} - V _{T-}) ⁽¹⁾			4.5 V	0.4		1.4	v
				6 V	0.6		1.6	
			I _{OH} = -20 μA	2 V to 6 V	V _{CC} – 0.1	V _{CC} - 0.002		
V _{OH}	High-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$	I _{OH} = -6 mA	4.5 V	4.0	4.3		V
			I _{OH} = -7.8 mA	6 V	5.4	5.75		
			I _{OL} = 20 μA	2 V to 6 V		0.002	0.1	
V _{OL}	Low-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 6 mA	4.5 V		0.18	0.30	V
			I _{OL} = 7.8 mA	6 V		0.22	0.33	
I _I	Input leakage current	$V_{I} = V_{CC} \text{ or } 0$		6 V		±100	±1000	nA
I _{CC}	Supply current	$V_{I} = V_{CC} \text{ or } 0, I_{C}$	_D = 0	6 V		0.1	2	μA
Ci	Input capacitance			2 V to 6 V			5	pF

(1) Guaranteed by design.

6.6 Timing Characteristics

C_L = 50 pF; over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information.

				Operating free	e-air temperat	ture (T _A)	
	PARAMETER	Vcc	25°C	–40°C	-40°C to 125°C		
				MIN M	AX MIN	MAX	
			2 V		32	17	
f _{clock}	ock Clock frequency	4.5 V		100	54		
			6 V		115	68	
			2 V	8	12	2	
		SRCLK or RCLK high or low	4.5 V	6	7		
+	Pulse duration	g. e. iett	6 V	6	7	,	
t _w			2 V	7	12	2	ns
		SRCLR or RCLR low	4.5 V	6	7	,	
			6 V	6	7	,	

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SN74HCS594 SCLS839A – OCTOBER 2020 – REVISED MAY 2021



C_L = 50 pF; over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information.

	<u> </u>	5 1		Operating	e (T _A)				
		PARAMETER	Vcc	25°C		-40°C to 125°C		UNIT	
				MIN	MAX	MIN MAX			
				2 V	11		16		
			SER before SRCLK↑	4.5 V	4		7		
			ONOLIN	6 V	4		5		
				2 V	15		24		
			SRCLK↑ before RCLK↑	4.5 V	5		9		
				6 V	5		7		
			SRCLR low before RCLK↑ SRCLR high (inactive) before SRCLK↑	2 V	16		27		
t _{su}	Setup time			4.5 V	7		10		ns
				6 V	5		8		1
				2 V	5		9		
				4.5 V	3		5		
				6 V	3		4		
			RCLR high	2 V	8		12		
			(inactive) before	4.5 V	4		5		
			RCLK↑	6 V	3		4		
				2 V	0		0		
t _h	Hold time		SER after SRCLK↑	4.5 V	0		0		ns
				6 V	0		0		

6.7 Switching Characteristics

C_L = 50 pF; over operating free-air temperature range (unless otherwise noted). See Parameter Measurement Information.

					Op	perating	free-air	temperat	ure (T _A))		
PARAMETER		FROM	то	V _{cc}		25°C		–40°C to 125°C				
					MIN	TYP	MAX	MIN	TYP	MAX		
				2 V	32			17				
f _{max}	Max switching frequency			4.5 V	100			54			MHz	
				6 V	115			68				
				2 V		19	30			45		
		SRCLK	Q _{H'}	4.5 V		7	11			17	í l	
	Propagation delay			6 V		6	9			12	ns	
t _{pd}		RCLK	Q _A - Q _H	2 V		19	30			45	115	
				4.5 V		7	11			17		
				6 V		6	9			12		
		SRCLR	Q _{H'}	2 V		18	27			55	-	
				4.5 V		7	11			17		
t	Propagation delay			6 V		6	9			15		
t _{PHL}				2 V		18	27			55	ns	
		RCLR	Q _A - Q _H	4.5 V		7	11			17		
				6 V		6	9			15		
				2 V			9			16		
t _t	Transition-time		Any output	4.5 V			5			9	ns	
				6 V			4			8		



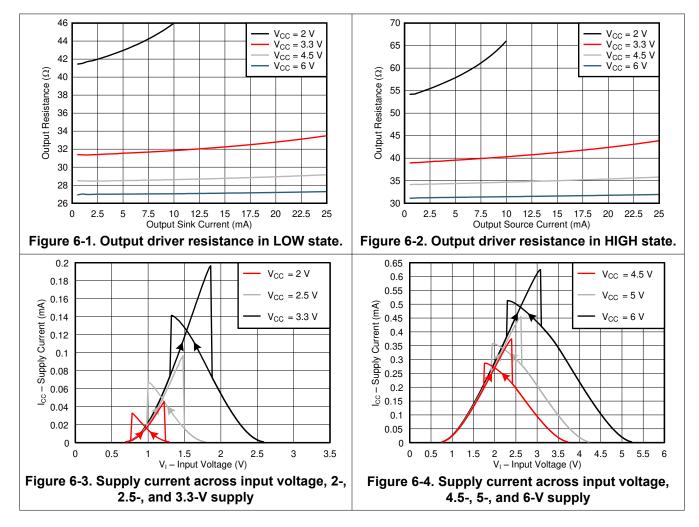
6.8 Operating Characteristics

over operating free-air temperature range; typical values measured at $T_A = 25^{\circ}C$ (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MA	X UNIT
C _{pd}	Power dissipation capacitance per gate	No load	2 V to 6 V		40	pF



6.9 Typical Characteristics



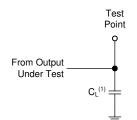


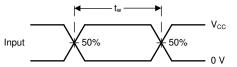
7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_t < 2.5 ns.

For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.







(1) C_L includes probe and test-fixture capacitance. Figure 7-1. Load Circuit for Push-Pull Outputs

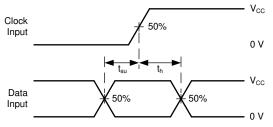
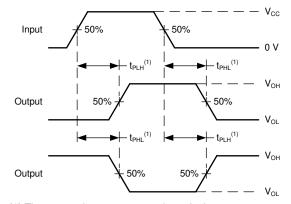
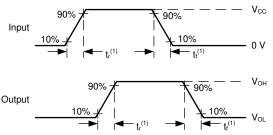


Figure 7-3. Voltage Waveforms, Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}. Figure 7-4. Voltage Waveforms Propagation Delays



(1) The greater between t_r and t_f is the same as t_t .

Figure 7-5. Voltage Waveforms, Input and Output Transition Times



8 Detailed Description

8.1 Overview

The SN74HCS594-Q1 is an 8-bit shift register that feeds an 8-bit D-type storage register. Both the shift register clock (SRCLK) and storage register clock (RCLK) are positive-edge triggered. If both clocks are connected together, the shift register always is one clock pulse ahead of the storage register. All inputs include Schmitt-triggers allowing for slow input transitions and providing more noise margin.

8.2 Functional Block Diagram

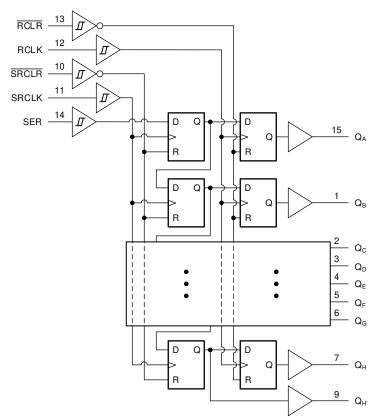


Figure 8-1. Logic Diagram (Positive Logic) for SN74HCS594

8.3 Feature Description

8.3.1 Balanced CMOS Push-Pull Outputs

This device includes balanced CMOS push-pull outputs. The term "balanced" indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

Unused push-pull CMOS outputs should be left disconnected.

8.3.2 CMOS Schmitt-Trigger Inputs

This device includes inputs with the Schmitt-trigger architecture. These inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics* table from the input to ground. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings* table, and the maximum input leakage current, given in the *Electrical Characteristics* table, using Ohm's law ($R = V \div I$).



The Schmitt-trigger input architecture provides hysteresis as defined by ΔV_T in the *Electrical Characteristics* table, which makes this device extremely tolerant to slow or noisy inputs. While the inputs can be driven much slower than standard CMOS inputs, it is still recommended to properly terminate unused inputs. Driving the inputs with slow transitioning signals will increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, please see Understanding Schmitt Triggers.

8.3.3 Clamp Diode Structure

The inputs and outputs to this device have both positive and negative clamping diodes as depicted in Electrical Placement of Clamping Diodes for Each Input and Output.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

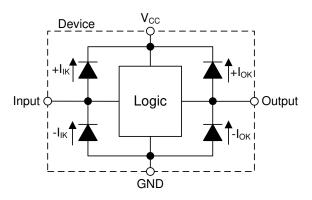


Figure 8-2. Electrical Placement of Clamping Diodes for Each Input and Output



8.4 Device Functional Modes

Function Table lists the functional modes of the SN74HCS594.

		INPUTS ⁽¹)		FUNCTION					
SER	SRCLK	SRCLR	RCLK	RCLR	FORCTION					
Х	Х	Х	Х	L	Shift register is cleared.					
Х	Х	L	Х	Х	Shift register is cleared.					
L	↑	Н	Х	Х						
н	1	н	х	х	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.					
x	x	н	1	х	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.					
x	Ť	н	î	х	First stage of the shift register goes high. Other stages store the data of previous stage, respectively.					

Table 8-1. Function Table

(1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

In this application, the SN74HCS594 is used to control seven-segment displays. Utilizing the serial output and combining a few of the input signals, this implementation reduces the number of I/O pins required to control the displays from sixteen to four. Unlike other I/O expanders, the SN74HCS594 does not need a communication interface for control. It can be easily operated with simple GPIO pins.

There is no practical limitation to how many SN74HCS594 devices can be cascaded. To add more, the serial output will need to be connected to the following serial input and the clocks will need to be connected accordingly. With separate control for the shift registers and output registers, the desired digit can be displayed while the data for the next digit is loaded into the shift register.

At power-up, the initial state of the shift registers and output registers are unknown. To give them a defined state, both registers need to be cleared. An RC can be connected to the \overline{SRCLR} and \overline{RCLR} pins as shown in the Typical application block diagram to initialize the shift and output registers to all zeros.



9.2 Typical Application

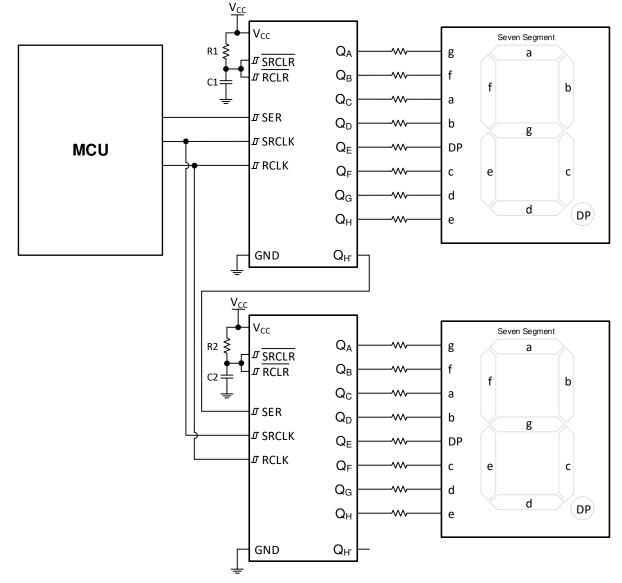


Figure 9-1. Typical application block diagram

9.2.1 Design Requirements

9.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics*.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74HCS594 plus the maximum static supply current, I_{CC} , listed in *Electrical Characteristics* and any transient current required for switching. The logic device can only source as much current as is provided by the positive supply source. Be sure not to exceed the maximum total current through V_{CC} listed in the *Absolute Maximum Ratings*.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74HCS594 plus the maximum supply current, I_{CC} , listed in *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current as can be sunk into its ground



connection. Be sure not to exceed the maximum total current through GND listed in the Absolute Maximum Ratings.

The SN74HCS594 can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the datasheet specifications. Larger capacitive loads can be applied, however it is not recommended to exceed 50 pF.

The SN74HCS594 can drive a load with total resistance described by $R_L \ge V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OH} and V_{OL} . When outputting in the high state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in CMOS Power Consumption and Cpd Calculation.

Thermal increase can be calculated using the information provided in Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.

CAUTION

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

9.2.1.2 Input Considerations

Input signals must cross $V_{t-(min)}$ to be considered a logic LOW, and $V_{t+(max)}$ to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74HCS594, as specified in the *Electrical Characteristics*, and the desired input transition rate. A 10-k Ω resistor value is often used due to these factors.

The SN74HCS594 has no input signal transition rate requirements because it has Schmitt-trigger inputs.

Another benefit to having Schmitt-trigger inputs is the ability to reject noise. Noise with a large enough amplitude can still cause issues. To know how much noise is too much, please refer to the $\Delta V_{T(min)}$ in the *Electrical Characteristics*. This hysteresis value will provide the peak-to-peak limit.

Unlike what happens with standard CMOS inputs, Schmitt-trigger inputs can be held at any valid value without causing huge increases in power consumption. The typical additional current caused by holding an input at a value other than V_{CC} or ground is plotted in the *Typical Characteristics*.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

9.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

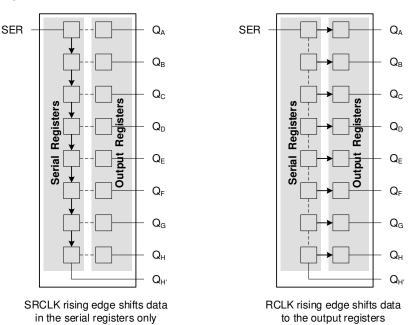
Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.



Refer to Feature Description section for additional information regarding the outputs for this device.

9.2.2 Detailed Design Procedure

- 1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout* section.
- Ensure the capacitive load at the output is ≤ 50 pF. This is not a hard limit, however it will ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74HCS594 to the receiving device(s).
- 3. Ensure the resistive load at the output is larger than $(V_{CC} / I_{O(max)}) \Omega$. This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in megaohms; much larger than the minimum calculated above.
- 4. Thermal issues are rarely a concern for logic gates, however the power consumption and thermal increase can be calculated using the steps provided in the application report, CMOS Power Consumption and Cpd Calculation.



9.2.3 Application Curve

Figure 9-2. Simplified functional diagram showing clock operation



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in given example layout image.

11 Layout

11.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

11.2 Layout Example

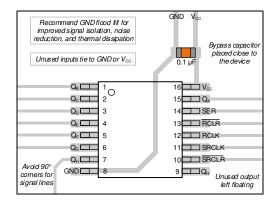


Figure 11-1. Example layout for the SN74HCS594 in the PW package.



12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, HCMOS Design Considerations application report (SCLA007)
- Texas Instruments, CMOS Power Consumption and Cpd Calculation application report (SDYA009)
- Texas Instruments, Designing With Logic application report

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.



13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74HCS594BQBR	ACTIVE	WQFN	BQB	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCS594	Samples
SN74HCS594DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HCS594	Samples
SN74HCS594PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HCS594	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74HCS594 :

• Automotive : SN74HCS594-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

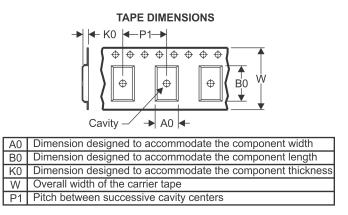
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCS594BQBR	WQFN	BQB	16	3000	180.0	12.4	2.8	3.8	1.2	4.0	12.0	Q1
SN74HCS594DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HCS594DR	SOIC	D	16	2500	330.0	16.4	6.6	9.3	2.1	8.0	16.0	Q1
SN74HCS594PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCS594PWR	TSSOP	PW	16	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

30-Jun-2021



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCS594BQBR	WQFN	BQB	16	3000	210.0	185.0	35.0
SN74HCS594DR	SOIC	D	16	2500	853.0	449.0	35.0
SN74HCS594DR	SOIC	D	16	2500	366.0	364.0	50.0
SN74HCS594PWR	TSSOP	PW	16	2000	853.0	449.0	35.0
SN74HCS594PWR	TSSOP	PW	16	2000	366.0	364.0	50.0

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

BQB 16

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

2.5 x 3.5, 0.5 mm pitch

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





BQB0016A

PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

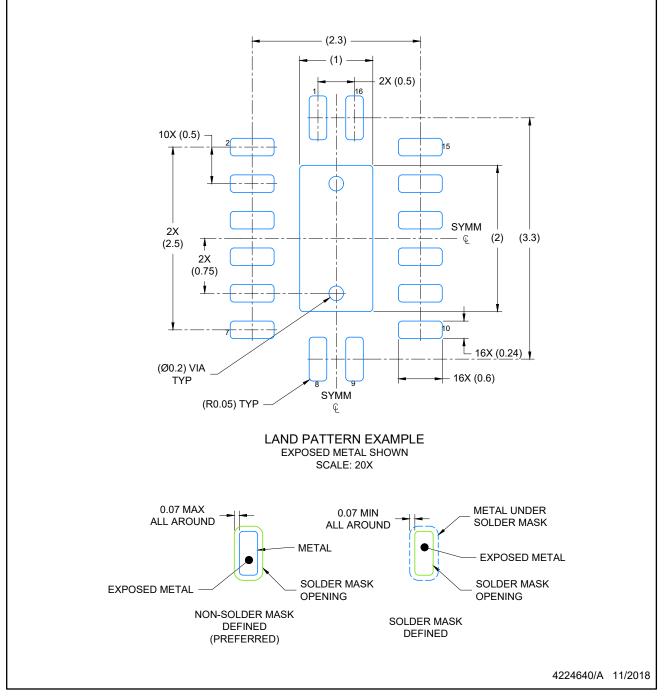


BQB0016A

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

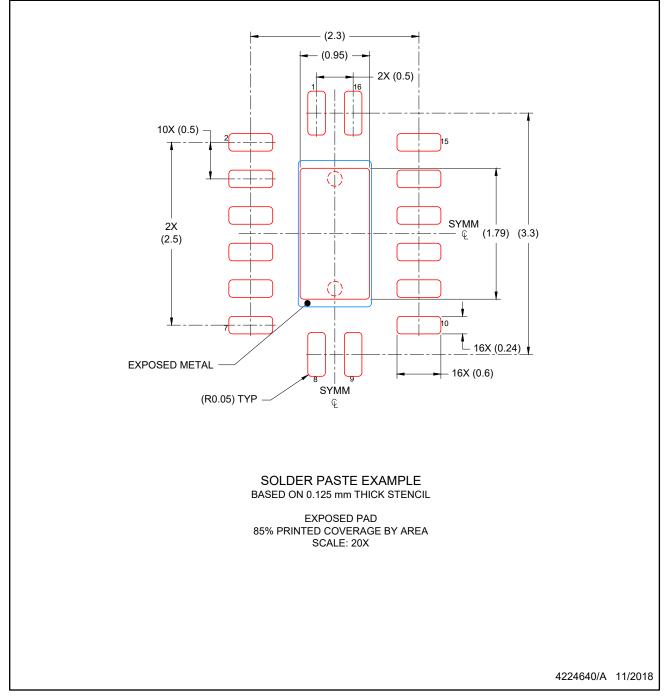


BQB0016A

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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